## INTEGRATED CIRCUITS

# DATA SHEET

# 74LVC16245A/ 74LVCH16245A

16-bit bus transceiver with direction pin; 5V tolerant (3-State)

Product specification Supersedes data of 1997 Aug 1 IC24 Data Handbook





## 16-bit bus transceiver with direction pin; 5V tolerant (3-State)

74LVC16245A/ 74LVCH16245A

#### **FEATURES**

- 5 volt tolerant inputs/outputs for interfacing with 5V logic
- Wide supply voltage range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- MULTIBYTE<sup>TM</sup> flow-through standard pin-out architecture
- Low inductance multiple power and ground pins for minimum noise and ground bounce
- Direct interface with TTL levels
- High impedance when V<sub>CC</sub> = 0
- All data inputs have bus hold (74LVCH16245A only)

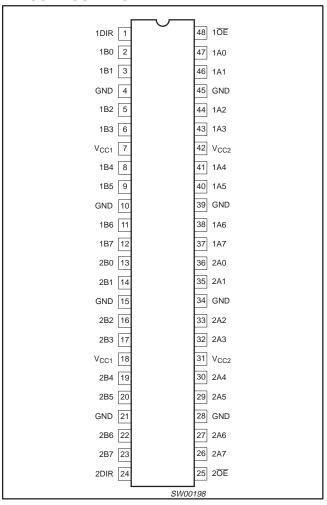
#### **DESCRIPTION**

The 74LVC(H)16245A is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families. Inputs can be driven from either 3.3V or 5V devices. In 3-State operation, outputs can handle 5V. These features allow the use of these devices in a mixed 3.3V/5V environment.

The 74LVC(H)16245A is a 16-bit transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. The 74LVC(H)16245A features two output enable (nOE) inputs for easy cascading and two send/receive (nDIR) inputs for direction control. nOE controls the outputs so that the buses are effectively isolated. This device can be used as two 8-bit transceivers or one 16-bit transceiver.

The 74LVCH16245A bus hold data inputs eliminates the need for extreme pull up resistors to hold unused inputs.

#### PIN CONFIGURATION



#### ORDERING INFORMATION

OTTO THE OTTO TO				
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74LVC16245A DL	VC16245A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74LVC16245A DGG	VC16245A DGG	SOT362-1
48-Pin Plastic SSOP Type III	-40°C to +85°C	74LVCH16245A DL	VCH16245A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74LVCH16245A DGG	VCH16245A DGG	SOT362-1

#### **QUICK REFERENCE DATA**

GND = 0V;  $T_{amb} = 25^{\circ}C$ ;  $t_r = t_f \le 2.5 \text{ ns}$ 

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay An to Bn; Bn to An	$C_L = 50pF$ $V_{CC} = 3.3V$	3.0	ns
C <sub>I</sub>	Input capacitance		5.0	pF
C <sub>I/O</sub>	Input/output capacitance		10	pF
C <sub>PD</sub>	Power dissipation capacitance per buffer	$V_I = GND \text{ to } V_{CC}^1$	30	pF

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;  $C_L$  = output load capacity in pF;  $f_o$  = output frequency in MHz;  $V_{CC}$  = supply voltage in V;

 $\Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$ 

 $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

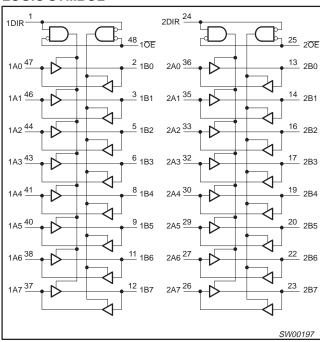
16-bit bus transceiver with direction pin; 5V tolerant (3-State)

74LVC16245A/ 74LVCH16245A

#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION			
1	1DIR	Direction control			
2, 3, 5, 6, 8, 9, 11, 12	1B0 to 1B7	Data inputs/outputs			
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)			
7, 18, 31, 42	V <sub>CC</sub>	Positive supply voltage			
13, 14, 16, 17, 19, 20, 22, 23	2B0 to 2B7	Data inputs/outputs			
24	2DIR	Direction control			
25	2 <del>OE</del>	Output enable input (active LOW)			
36, 35, 33, 32, 30, 29, 27, 26	2A0 to 2A7	Data inputs/outputs			
47, 46, 44, 43, 41, 40, 38, 37	1A0 to 1A7	Data inputs/outputs			
48	1 <del>OE</del>	Output enable input (active LOW)			

## **LOGIC SYMBOL**



### **FUNCTION TABLE**

INP	JTS	INPUTS/OUTPUT				
nOE	nDIR	nAn	nBn			
L	L	A = B	inputs			
L	Н	inputs	B = A			
Н	Х	Z	Z			

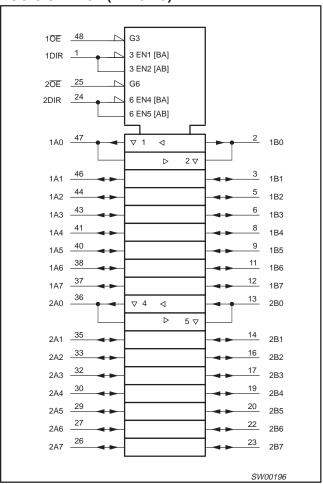
H = HIGH voltage level

L = LOW voltage level

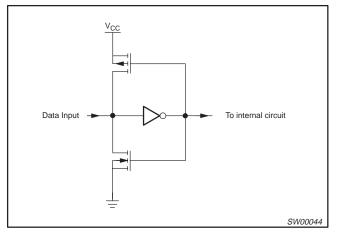
X = don't care

Z = high impedance OFF-state

### LOGIC SYMBOL (IEEE/IEC)



#### **BUS HOLD CIRCUIT**



# 16-bit bus transceiver with direction pin; 5V tolerant (3-State)

74LVC16245A/ 74LVCH16245A

#### RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	ITS	UNIT
STWIDOL	TANAMETER	CONDITIONS	MIN.	MAX.	
V <sub>CC</sub>	DC supply voltage (for max. speed performance)		2.7	3.6	V
V <sub>CC</sub>	DC supply voltage (for low-voltage applications)		1.2	3.6	V
VI	DC Input voltage range		0	5.5	V
Vo	DC output voltage range; output HIGH or LOW state		0	V <sub>CC</sub>	V
Vo	DC output voltage range; output 3-State		0	5.5	V
T <sub>amb</sub>	Operating ambient temperature range in free air		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7V$ $V_{CC} = 2.7 \text{ to } 3.6V$	0	20 10	ns/V

## **ABSOLUTE MAXIMUM RATINGS**<sup>1</sup>

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	LIN	IITS	UNIT
STWIBOL	FARAMETER	CONDITIONS	MIN	MAX	l Own
V <sub>CC</sub>	DC supply voltage		-0.5	+6.5	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	-	-50	mA
V <sub>I</sub>	DC input voltage	Note 2	-0.5	+6.5	V
I <sub>OK</sub>	DC output diode current	$V_O > V_{CC}$ or $V_O < 0$	-	±50	mA
Vo	DC output voltage; output HIGH or LOW state	Note 2	-0.5	V <sub>CC</sub> + 0.5	V
Vo	DC output voltage; output 3-State	Note 2	-0.5	6.5	V
Io	DC output source or sink current	$V_O = 0$ to $V_{CC}$	-	±50	mA
I <sub>GND</sub> , I <sub>CC</sub>	DC V <sub>CC</sub> or GND current		-	±100	mA
T <sub>stg</sub>	Storage temperature range		-65	+150	°C
	Power dissipation per package				
P <sub>tot</sub>	– SO package	Above +70°C derate linearly 8mW/K		500	mW
	<ul> <li>SSOP and TSSOP package</li> </ul>	Above +60°C derate linearly 5.5mW/K		500	

#### NOTES

<sup>1.</sup> Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>2.</sup> The input and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.

## 16-bit bus transceiver with direction pin; 5V tolerant (3-State)

74LVC16245A/ 74LVCH16245A

#### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V)

			L	IMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -	UNI <sup>.</sup>		
			MIN	TYP <sup>1</sup>	MAX	1
	LUCIU Ll t t t	V <sub>CC</sub> = 1.2V	V <sub>CC</sub>			V
$V_{IH}$	HIGH level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V	2.0			7 °
\ /	LOW love land water	V <sub>CC</sub> = 1.2V			GND	V
$V_{IL}$	LOW level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V			0.8	7 °
		$V_{CC} = 2.7V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -12$ mA	V <sub>CC</sub> -0.5			
.,		$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -100\mu A$	V <sub>CC</sub> -0.2	V <sub>CC</sub>		] ,
V <sub>OH</sub>	HIGH level output voltage	$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -18$ mA	V <sub>CC</sub> -0.6			]
		$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -24$ mA	V <sub>CC</sub> -0.8			1
		$V_{CC} = 2.7V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 12$ mA			0.40	
$V_{OL}$	LOW level output voltage $V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu\text{A}$				0.20	<b>1</b> v
		$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 24$ mA			0.55	1
I <sub>I</sub>	Input leakage current	V <sub>CC</sub> = 3.6V; V <sub>I</sub> = 5.5V or GND		±0.1	±5	μΑ
l <sub>OZ</sub>	3-State output OFF-state current <sup>7</sup>	$V_{CC} = 3.6V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $V_O = 5.5V$ or GND		0.1	±5	μΑ
I <sub>off</sub>	Power off leakage supply	$V_{CC} = 0.0V; V_{I} \text{ or } V_{O} = 5.5V$		0.1	±10	μΔ
I <sub>CC</sub>	Quiescent supply current	$V_{CC} = 3.6V; V_{I} = V_{CC} \text{ or GND}; I_{O} = 0$		0.1	20	μΑ
Δl <sub>CC</sub>	Additional quiescent supply current per input pin	$V_{CC} = 2.7V \text{ to } 3.6V; V_I = V_{CC} - 0.6V; I_O = 0$		5	500	μА
I <sub>BHL</sub>	Bus hold LOW sustaining current	$V_{CC} = 3.0V; V_I = 0.8V^{2, 3, 4}$	75			μΔ
I <sub>BHH</sub>	Bus hold HIGH sustaining current	$V_{CC} = 3.0V; V_{I} = 2.0V^{2, 3, 4}$	-75			μΑ
I <sub>BHLO</sub>	Bus hold LOW overdrive current	V <sub>CC</sub> = 3.6V <sup>2, 3, 5</sup>	500			μA
Івнно	Bus hold HIGH overdrive current	V <sub>CC</sub> = 3.6V <sup>2, 3, 5</sup>	-500			μA

- All typical values are at V<sub>CC</sub> = 3.3V and T<sub>amb</sub> = 25°C.
   Valid for data inputs of bus hold parts (LVCH16-A) only.
- 3. For data inputs only, control inputs do not have a bus hold circuit.
- The specified sustaining current at the data input holds the input below the specified V<sub>I</sub> level.
- 5. The specified overdrive current at the data input forces the data input to the opposite logic input state.
- 6. For bus hold parts, the bus hold circuit is switched off when  $V_i$  exceeds  $V_{CC}$  allowing 5.5V on the input terminal.
- 7. For I/O ports the parameter I<sub>OZ</sub> includes the input leakage current.

### **AC CHARACTERISTICS**

GND = 0V;  $t_R = t_F = 2.5$ ns;  $C_L = 50$ pF;  $R_L = 500\Omega$ ;  $T_{amb} = -40$ °C to +85°C.

				LIMITS					
SYMBOL	PARAMETER	WAVEFORM	V <sub>CC</sub>	$V_{CC} = 3.3V \pm 0.3V$			: 2.7V	V <sub>CC</sub> = 1.2V	UNIT
			MIN	TYP <sup>1</sup>	MAX	MIN	MAX	TYP	
t <sub>PHL</sub> t <sub>PLH</sub>	Propagation delay nAn to nBn; nBn to nAn	1	1.5	3	4.5	1.5	5.5	13	ns
t <sub>PZH</sub>	3-State output enable time nOE to nAn; nOE to nBn	2, 3	1.5	4	6.1	1.5	7.1	15	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	3-State output disable time nOE to nAn; nOE to nBn	2, 3	1.5	4	5.6	1.5	6.6	11	ns

<sup>1.</sup> All typical values are at  $V_{CC}$  = 3.3V and  $T_{amb}$  = 25°C.

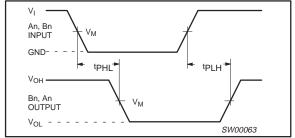
# 16-bit bus transceiver with direction pin; 5V tolerant (3-State)

74LVC16245A/ 74LVCH16245A

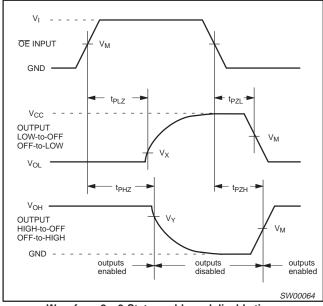
#### AC WAVEFORMS

 $V_M$  = 1.5V at  $V_{CC} \ge$  2.7V;  $V_M$  = 0.5  $V_{CC}$  at  $V_{CC} <$  2.7V. V<sub>OL</sub> and V<sub>OH</sub> are the typical output voltage drop that occur with the

V<sub>X</sub> = V<sub>OL</sub> + 0.3V at V<sub>CC</sub>  $\geq$  2.7V; V<sub>X</sub> = V<sub>OL</sub> + 0.1 V<sub>CC</sub> at V<sub>CC</sub> < 2.7V V<sub>Y</sub> = V<sub>OH</sub> -0.3V at V<sub>CC</sub>  $\geq$  2.7V; V<sub>Y</sub> = V<sub>OH</sub> - 0.1 V<sub>CC</sub> at V<sub>CC</sub> < 2.7V

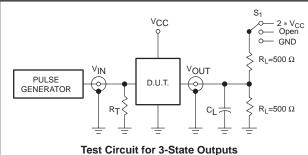


Waveform 1. Input (nAn, nBn) to output (nBn, nAn) propagation delay times



Waveform 2. 3-State enable and disable times

#### **TEST CIRCUIT**



#### **SWITCH POSITION**

TEST	SWITCH
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	2 * V <sub>CC</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

V <sub>CC</sub>	V <sub>IN</sub>
< 2.7V 2.7 – 3.6V	V <sub>CC</sub> 2.7V

#### **DEFINITIONS**

R<sub>L</sub> = Load resistor

C<sub>L</sub> = Load capacitance includes jig and probe capacitance

 $R_T$  = Termination resistance should be equal to  $Z_{OUT}$ of pulse generators.

SW00047

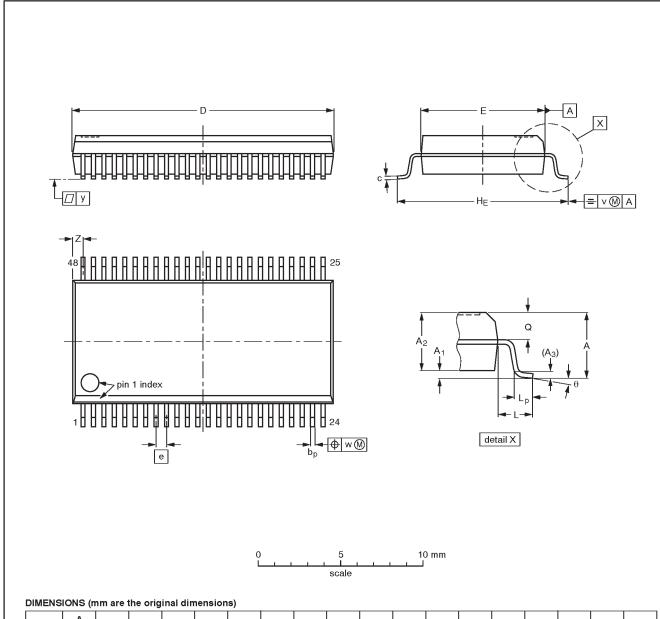
Waveform 3. Load circuitry for switching times

# 16-bit bus transceiver with direction pin; 5V tolerant (3-State)

74LVC16245A/ 74LVCH16245A

## SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



UNIT	A max.	Α1	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1330E DATE	
SOT370-1		MO-118AA			<del>93-11-02</del> 95-02-04	

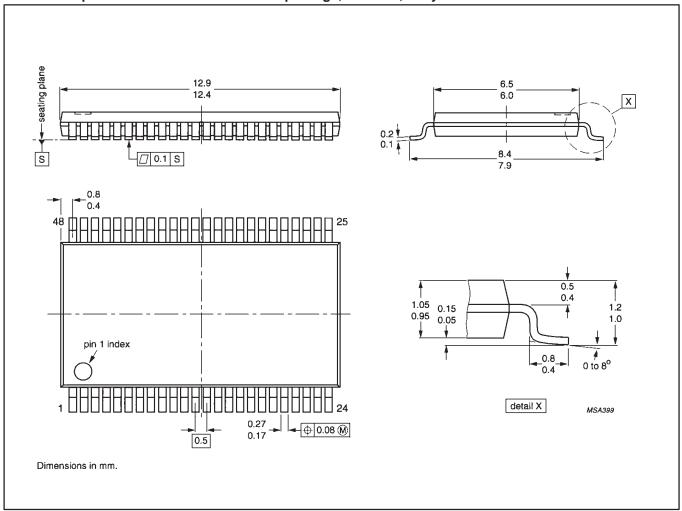
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16-bit bus transceiver with direction pin; 5V tolerant (3-State)

74LVC16245A/ 74LVCH16245A

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm

SOT362-1



16-bit bus transceiver with direction pin; 5V tolerant (3-State)

74LVC16245A/ 74LVCH16245A

**NOTES** 

16-bit bus transceiver with direction pin; 5V tolerant (3-State)

74LVC16245A/ 74LVCH16245A

DEFINITIONS		
Data Sheet Identification	Product Status	Definition
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
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print code Date of release: 05-96

Document order number: 9397-750-04531

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